

# TA8277H

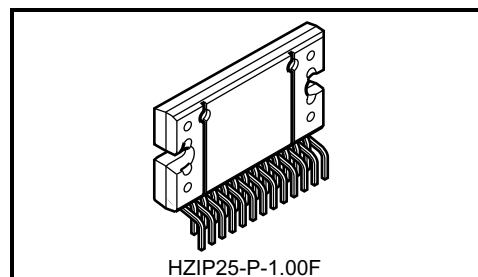
Max Power 43 W BTL × 4 ch Audio Power IC

The TA8277H is 4 ch BTL audio power amplifier for car audio application.

This IC can generate more high power:  $POUT_{MAX} = 43\text{ W}$  as it is included the pure complementary PNP and NPN transistor output stage.

It is designed low distortion ratio for 4 ch BTL audio power amplifier, built-in stand-by function and muting function.

Additionally, the AUX amplifier and various kind of protector for car audio use is built-in.



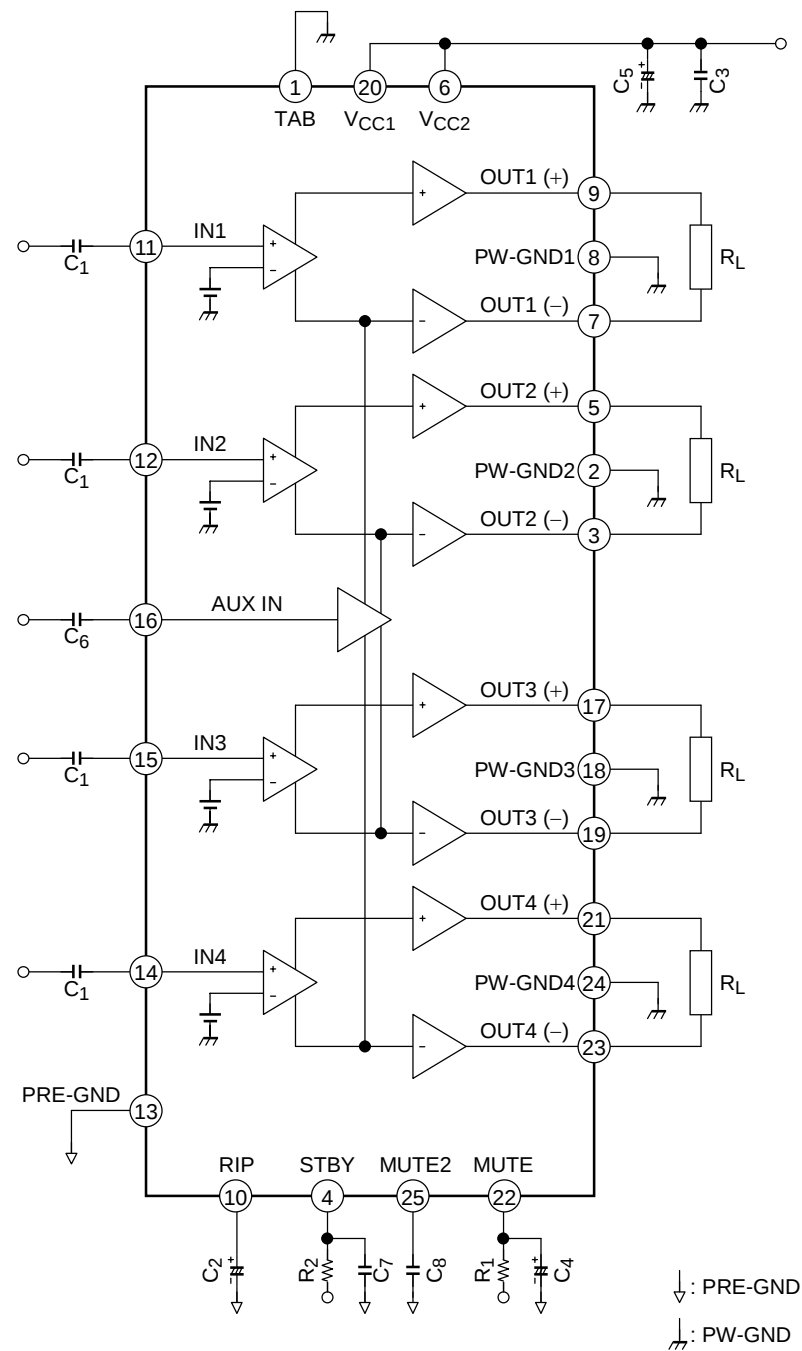
HZIP25-P-1.00F

Weight: 7.7 g (typ.)

## Features

- High power:  $POUT_{MAX} (1) = 43\text{ W (typ.)}$   
( $V_{CC} = 14.4\text{ V}$ ,  $f = 1\text{ kHz}$ , EIAJ max,  $R_L = 4\ \Omega$ )  
:  $POUT_{MAX} (2) = 40\text{ W (typ.)}$   
( $V_{CC} = 13.7\text{ V}$ ,  $f = 1\text{ kHz}$ , EIAJ max,  $R_L = 4\ \Omega$ )  
:  $POUT (1) = 28\text{ W (typ.)}$   
( $V_{CC} = 14.4\text{ V}$ ,  $f = 1\text{ kHz}$ , THD = 10%,  $R_L = 4\ \Omega$ )  
:  $POUT (2) = 24\text{ W (typ.)}$   
( $V_{CC} = 13.2\text{ V}$ ,  $f = 1\text{ kHz}$ , THD = 10%,  $R_L = 4\ \Omega$ )
- Low distortion ratio: THD = 0.02% (typ.)  
( $V_{CC} = 13.2\text{ V}$ ,  $f = 1\text{ kHz}$ ,  $POUT = 5\text{ W}$ ,  $R_L = 4\ \Omega$ )
- Low noise:  $V_{NO} = 0.10\text{ mV}_{rms}$  (typ.)  
( $V_{CC} = 13.2\text{ V}$ ,  $R_g = 0\ \Omega$ ,  $G_V = 26\text{ dB}$ , BW = 20 Hz~20 kHz)
- Built-in stand-by switch function (pin 4)
- Built-in muting function (pin 22)
- Built-in AUX amplifier from single input to 4 channels output (pin 16)
- Built-in various protection circuit  
: Thermal shut down, over voltage, out to GND, out to  $V_{CC}$ , out to out short
- Operating supply voltage:  $V_{CC} (opr) = 9\sim 18\text{ V}$

Block Diagram



## Maximum Ratings (Ta = 25°C)

| Characteristics             | Symbol                  | Rating  | Unit |
|-----------------------------|-------------------------|---------|------|
| Peak supply voltage (0.2 s) | V <sub>CC</sub> (surge) | 50      | V    |
| DC supply voltage           | V <sub>CC</sub> (DC)    | 25      | V    |
| Operation supply voltage    | V <sub>CC</sub> (opr)   | 18      | V    |
| Output current (peak)       | I <sub>O</sub> (peak)   | 9       | A    |
| Power dissipation           | P <sub>D</sub> (Note1)  | 125     | W    |
| Operation temperature       | T <sub>opr</sub>        | -40~85  | °C   |
| Storage temperature         | T <sub>stg</sub>        | -55~150 | °C   |

Note 1: Package thermal resistance  $\theta_{j-T} = 1^{\circ}\text{C/W}$  (typ.)  
(Ta = 25°C, with infinite heat sink)

## Electrical Characteristics

(unless otherwise specified, V<sub>CC</sub> = 13.2 V, f = 1 kHz, R<sub>L</sub> = 4  $\Omega$ , Ta = 25°C)

| Characteristics              | Symbol                   | Test Circuit | Test Condition                                                                                   | Min  | Typ. | Max             | Unit       |
|------------------------------|--------------------------|--------------|--------------------------------------------------------------------------------------------------|------|------|-----------------|------------|
| Quiescent current            | I <sub>CCQ</sub>         | —            | V <sub>IN</sub> = 0                                                                              | —    | 200  | 400             | mA         |
| Output power                 | P <sub>OUT</sub> MAX (1) | —            | V <sub>CC</sub> = 14.4 V, max Power                                                              | —    | 43   | —               | W          |
|                              | P <sub>OUT</sub> MAX (2) | —            | V <sub>CC</sub> = 13.7 V, max Power                                                              | —    | 40   | —               |            |
|                              | P <sub>OUT</sub> (1)     | —            | V <sub>CC</sub> = 14.4 V, THD = 10%                                                              | —    | 28   | —               |            |
|                              | P <sub>OUT</sub> (2)     | —            | THD = 10%                                                                                        | 22   | 24   | —               |            |
| Total harmonic distortion    | THD                      | —            | P <sub>OUT</sub> = 5 W                                                                           | —    | 0.02 | 0.2             | %          |
| Voltage gain                 | G <sub>V</sub>           | —            | V <sub>OUT</sub> = 0.775 Vrms (0dBm)                                                             | 24   | 26   | 28              | dB         |
| Voltage gain ratio           | $\Delta G_V$             | —            | V <sub>OUT</sub> = 0.775 Vrms (0dBm)                                                             | -1.0 | 0    | 1.0             |            |
| Output noise voltage         | V <sub>NO</sub> (1)      | —            | R <sub>g</sub> = 0 $\Omega$ , DIN45405                                                           | —    | 0.12 | —               | mVrms      |
|                              | V <sub>NO</sub> (2)      | —            | R <sub>g</sub> = 0 $\Omega$ , BW = 20 Hz~20 kHz                                                  | —    | 0.10 | 0.35            |            |
| Ripple rejection ratio       | R.R.                     | —            | f <sub>rip</sub> = 100 Hz, R <sub>g</sub> = 620 $\Omega$<br>V <sub>rip</sub> = 0.775 Vrms (0dBm) | 40   | 50   | —               | dB         |
| Cross talk                   | C.T.                     | —            | R <sub>g</sub> = 620 $\Omega$<br>V <sub>OUT</sub> = 0.775 Vrms (0dBm)                            | —    | 65   | —               | dB         |
| Output offset voltage        | V <sub>OFFSET</sub>      | —            | —                                                                                                | -150 | 0    | +150            | mV         |
| Input resistance             | R <sub>IN</sub>          | —            | —                                                                                                | —    | 90   | —               | k $\Omega$ |
| Stand-by current             | I <sub>SB</sub>          | —            | Stand-by condition                                                                               | —    | 2    | 10              | $\mu$ A    |
| Stand-by control voltage     | V <sub>SB</sub> H        | —            | Power: ON                                                                                        | 3.0  | —    | V <sub>CC</sub> | V          |
|                              | V <sub>SB</sub> L        | —            | Power: OFF                                                                                       | 0    | —    | 1.5             |            |
| Mute control voltage (Note2) | V <sub>M</sub> H         | —            | Mute: OFF                                                                                        | Open |      |                 | —          |
|                              | V <sub>M</sub> L         | —            | Mute: ON, R <sub>1</sub> = 10 k $\Omega$                                                         | 0    | —    | 0.5             | V          |
| Mute attenuation             | ATT M                    | —            | Mute: ON,<br>V <sub>OUT</sub> = 7.75 Vrms (20dBm) at<br>Mute: OFF.                               | 80   | 90   | —               | dB         |

Note 2: Muting function have to be controlled by open and low logic, which logic is a transistor, FET and  $\mu$ -COM port of I<sub>MUTE</sub> > 50  $\mu$ A ability.

This means than the mute control terminal : pin 22 must not be pulled-up.

## Test Circuit

